

# CD54HC257, CD74HC257, CD54HCT257

Data sheet acquired from Harris Semiconductor SCHS171D

November 1997 - Revised October 2003

# High-Speed CMOS Logic Quad 2-Input Multiplexer with Three-State Non-Inverting Outputs

#### **Features**

- · Buffered Inputs
- Typical Propagation Delay (In to Output) = 12ns at V<sub>CC</sub> = 5V, C<sub>L</sub> = 15pF, T<sub>A</sub> = 25°C
- Fanout (Over Temperature Range)
  - Standard Outputs............ 10 LSTTL Loads
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity:  $N_{IL}$  = 30%,  $N_{IH}$  = 30% of  $V_{CC}$  at  $V_{CC}$  = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility, V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
  - CMOS Input Compatibility,  $I_I \le 1\mu A$  at  $V_{OL}$ ,  $V_{OH}$

# Description

The 'HC257 and 'HCT257 are quad 2-input multiplexers which select four bits of data from two sources under the control of a common Select Input (S). The Output Enable input  $(\overline{OE})$  is active LOW. When  $\overline{OE}$  is HIGH, all of the outputs (1Y-4Y) are in the high impedance state regardless of

all other input conditions.

Moving data from two groups of registers to four common output buses is a common use of the 257. The state of the Select input determines the particular register from which the data comes. It can also be used as a function generator.

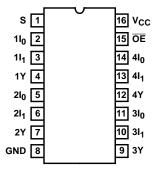
## **Ordering Information**

| PART NUMBER   | TEMP. RANGE<br>(°C) | PACKAGE      |
|---------------|---------------------|--------------|
| CD54HC257F3A  | -55 to 125          | 16 Ld CERDIP |
| CD54HCT257F3A | -55 to 125          | 16 Ld CERDIP |
| CD74HC257E    | -55 to 125          | 16 Ld PDIP   |
| CD74HC257M    | -55 to 125          | 16 Ld SOIC   |
| CD74HC257MT   | -55 to 125          | 16 Ld SOIC   |
| CD74HC257M96  | -55 to 125          | 16 Ld SOIC   |
| CD74HCT257E   | -55 to 125          | 16 Ld PDIP   |
| CD74HCT257M   | -55 to 125          | 16 Ld SOIC   |
| CD74HCT257MT  | -55 to 125          | 16 Ld SOIC   |
| CD74HCT257M96 | -55 to 125          | 16 Ld SOIC   |

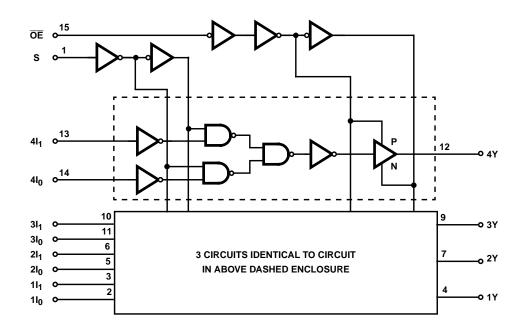
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

#### **Pinout**

CD54HC257, CD54HCT257 (CERDIP) CD74HC257, CD74HCT257 (PDIP, SOIC) TOP VIEW



# Functional Diagram



**TRUTH TABLE** 

| OUTPUT<br>ENABLE | SELECT<br>INPUT | DATA I         | ОИТРИТ |   |  |
|------------------|-----------------|----------------|--------|---|--|
| ŌĒ               | S               | l <sub>0</sub> | Y      |   |  |
| Н                | Х               | Х              | Х      | Z |  |
| L                | L               | L              | Х      | L |  |
| L                | L               | Н              | Х      | Н |  |
| L                | Н               | Х              | L      | L |  |
| L                | Н               | X              | Н      | Н |  |

H= High Voltage Level L= Low Voltage Level

X= Don't Care

Z= High Impedance, OFF State

# **Absolute Maximum Ratings**

## DC Supply Voltage, $V_{CC}$ . . . . . -0.5V to 7V DC Input Diode Current, I<sub>IK</sub> For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ..... $\pm 20$ mA DC Output Diode Current, $I_{OK}$ For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ......±20mA DC Drain Current, per Output, IO For $-0.5V < V_O < V_{CC} + 0.5V$ ......±35mA DC Output Source or Sink Current per Output Pin, IO

#### **Thermal Information**

| Thermal Resistance (Typical, Note 1)     | $\theta_{JA}$ (°C/W) |
|--|----------------------|
| E (PDIP) Package                         | . 67                 |
| M (SOIC) Package                         |                      |
| Maximum Junction Temperature             | 150 <sup>o</sup> C   |
| Maximum Storage Temperature Range        | -65°C to 150°C       |
| Maximum Lead Temperature (Soldering 10s) | 300°C                |
| (SOIC - Lead Tips Only)                  |                      |

## **Operating Conditions**

| Temperature Range, T <sub>A</sub> 55°C to 125°C                                   |
|---|
| Supply Voltage Range, V <sub>CC</sub>   |
| HC Types2V to 6V  |
| HCT Types   |
| DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub> |
| Input Rise and Fall Time  |
| 2V  |
| 4.5V 500ns (Max)  |
| 6V  |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

## **DC Electrical Specifications**

|                          |                 |                                       | TEST DINDITIONS 25°C |                     | -40°C T | O 85°C | -55°C T |      |      |      |      |       |
|--------------------------|-----------------|---------------------------------------|----------------------|---------------------|---------|--------|---------|------|------|------|------|-------|
| PARAMETER                | SYMBOL          | V <sub>I</sub> (V)                    | I <sub>O</sub> (mA)  | V <sub>CC</sub> (V) | MIN     | TYP    | MAX     | MIN  | MAX  | MIN  | MAX  | UNITS |
| HC TYPES                 |                 |                                       |                      |                     |         |        | -       |      |      |      |      |       |
| High Level Input         | V <sub>IH</sub> | -                                     | -                    | 2                   | 1.5     | -      | -       | 1.5  | -    | 1.5  | -    | V     |
| Voltage                  |                 |                                       |                      | 4.5                 | 3.15    | -      | -       | 3.15 | -    | 3.15 | -    | V     |
|                          |                 |                                       |                      | 6                   | 4.2     | -      | -       | 4.2  | -    | 4.2  | -    | V     |
| Low Level Input          | V <sub>IL</sub> | -                                     | -                    | 2                   | -       | -      | 0.5     | -    | 0.5  | -    | 0.5  | V     |
| Voltage                  |                 |                                       |                      | 4.5                 | -       | -      | 1.35    | -    | 1.35 | -    | 1.35 | V     |
|                          |                 |                                       |                      | 6                   | -       | -      | 1.8     | -    | 1.8  | -    | 1.8  | V     |
| High Level Output        | V <sub>OH</sub> | V <sub>IH</sub> or<br>V <sub>IL</sub> | -0.02                | 2                   | 1.9     | -      | -       | 1.9  | -    | 1.9  | -    | V     |
| Voltage<br>CMOS Loads    |                 |                                       | -0.02                | 4.5                 | 4.4     | -      | -       | 4.4  | -    | 4.4  | -    | V     |
|                          |                 |                                       | -0.02                | 6                   | 5.9     | -      | -       | 5.9  | -    | 5.9  | -    | V     |
| High Level Output        | 1               |                                       | -6                   | 4.5                 | 3.98    | -      | -       | 3.84 | -    | 3.7  | -    | V     |
| Voltage<br>TTL Loads     |                 |                                       | -7.8                 | 6                   | 5.48    | -      | -       | 5.34 | -    | 5.2  | -    | V     |
| Low Level Output         | V <sub>OL</sub> | V <sub>IH</sub> or                    | 0.02                 | 2                   | -       | -      | 0.1     | -    | 0.1  | -    | 0.1  | V     |
| Voltage<br>CMOS Loads    |                 | $V_{IL}$                              | 0.02                 | 4.5                 | -       | -      | 0.1     | -    | 0.1  | -    | 0.1  | V     |
|                          |                 |                                       | 0.02                 | 6                   | -       | -      | 0.1     | -    | 0.1  | -    | 0.1  | V     |
| Low Level Output         | 7               |                                       | 6                    | 4.5                 | -       | -      | 0.26    | -    | 0.33 | -    | 0.4  | V     |
| Voltage<br>TTL Loads     |                 |                                       | 7.8                  | 6                   | -       | -      | 0.26    | -    | 0.33 | -    | 0.4  | V     |
| Input Leakage<br>Current | II              | V <sub>CC</sub> or<br>GND             | -                    | 6                   | -       | -      | ±0.1    | -    | ±1   | -    | ±1   | μА    |

# DC Electrical Specifications (Continued)

|  |                              |                                       | ST<br>ITIONS        |                     |      | 25°C |      | -40°C T | O 85°C | -55°C T | O 125°C |       |
|--|------------------------------|---------------------------------------|---------------------|---------------------|------|------|------|---------|--------|---------|---------|-------|
| PARAMETER  | SYMBOL                       | V <sub>I</sub> (V)                    | I <sub>O</sub> (mA) | V <sub>CC</sub> (V) | MIN  | TYP  | MAX  | MIN     | MAX    | MIN     | MAX     | UNITS |
| Quiescent Device<br>Current  | Icc                          | V <sub>CC</sub> or<br>GND             | 0                   | 6                   | -    | -    | 8    | -       | 80     | -       | 160     | μА    |
| Three-State Leakage<br>Current                                       | l <sub>OZ</sub>              | V <sub>IL</sub> or<br>V <sub>IH</sub> | -                   | 6                   | -    | -    | ±0.5 | -       | ±5     | -       | ±10     | μΑ    |
| HCT TYPES  | •                            |                                       |                     |                     |      |      |      |         |        |         |         | •     |
| High Level Input<br>Voltage  | V <sub>IH</sub>              | -                                     | -                   | 4.5 to<br>5.5       | 2    | -    | -    | 2       | -      | 2       | -       | V     |
| Low Level Input<br>Voltage   | V <sub>IL</sub>              | -                                     | -                   | 4.5 to<br>5.5       | -    | -    | 0.8  | -       | 0.8    | -       | 0.8     | V     |
| High Level Output<br>Voltage<br>CMOS Loads                           | V <sub>OH</sub>              | V <sub>IH</sub> or<br>V <sub>IL</sub> | -0.02               | 4.5                 | 4.4  | -    | -    | 4.4     | -      | 4.4     | -       | V     |
| High Level Output<br>Voltage<br>TTL Loads                            |                              |                                       | -6                  | 4.5                 | 3.98 | -    | -    | 3.84    | -      | 3.7     | -       | V     |
| Low Level Output<br>Voltage<br>CMOS Loads                            | V <sub>OL</sub>              | V <sub>IH</sub> or<br>V <sub>IL</sub> | 0.02                | 4.5                 | -    | -    | 0.1  | -       | 0.1    | -       | 0.1     | V     |
| Low Level Output<br>Voltage<br>TTL Loads                             |                              |                                       | 6                   | 4.5                 | -    | -    | 0.26 | -       | 0.33   | -       | 0.4     | V     |
| Input Leakage<br>Current   | II                           | V <sub>CC</sub> to<br>GND             | 0                   | 5.5                 | -    | -    | ±0.1 | -       | ±1     | -       | ±1      | μΑ    |
| Quiescent Device<br>Current  | I <sub>CC</sub>              | V <sub>CC</sub> or<br>GND             | 0                   | 5.5                 | -    | -    | 8    | -       | 80     | -       | 160     | μΑ    |
| Additional Quiescent<br>Device Current Per<br>Input Pin: 1 Unit Load | ΔI <sub>CC</sub><br>(Note 2) | V <sub>CC</sub><br>-2.1               | -                   | 4.5 to<br>5.5       | -    | 100  | 360  | -       | 450    | -       | 490     | μΑ    |
| Three-State Leakage<br>Current                                       | loz                          | V <sub>IL</sub> or<br>V <sub>IH</sub> | -                   | 5.5                 | -    | -    | ±0.5 | -       | ±5     | -       | ±10     | μΑ    |

## NOTE:

# **HCT Input Loading Table**

| INPUT | UNIT LOADS |  |  |  |  |  |
|-------|------------|--|--|--|--|--|
| Data  | 0.95       |  |  |  |  |  |
| S     | 3          |  |  |  |  |  |
| ŌĒ    | 0.6        |  |  |  |  |  |

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications table, e.g., 360 $\mu A$  max at  $25^{o}C.$ 

<sup>2.</sup> For dual-supply systems theoretical worst case ( $V_I$  = 2.4V,  $V_{CC}$  = 5.5V) specification is 1.8mA.

# **Switching Specifications** Input $t_r$ , $t_f = 6ns$

|  |                                       | TEST                  |                     | 25  | o <sub>C</sub> | -40°C TO 85°C | -55°C TO 125°C |          |
|--|---------------------------------------|-----------------------|---------------------|-----|----------------|---------------|----------------|----------|
| PARAMETER  | SYMBOL                                | CONDITIONS            | V <sub>CC</sub> (V) | TYP | MAX            | MAX           | MAX            | UNITS    |
| HC TYPES   |                                       |                       |                     |     |                |               |                |          |
| Propagation Delay<br>In to Y                     | t <sub>PLH</sub> , t <sub>PHL</sub>   | C <sub>L</sub> = 50pF | 2                   | -   | 150            | 190           | 225            | ns       |
| III to 1   |                                       |                       | 4.5                 | •   | 30             | 38            | 45             | ns       |
|  |                                       | C <sub>L</sub> = 15pF | 5                   | 12  | -              | -             | -              | ns       |
|  |                                       | CL = 50pF             | 6                   | -   | 26             | 33            | 38             | ns       |
| Propagation Delay                                | t <sub>PLH</sub> , t <sub>PHL</sub>   | C <sub>L</sub> = 50pF | 2                   | -   | 175            | 220           | 265            | ns       |
| S to Y   |                                       |                       | 4.5                 | -   | 35             | 44            | 53             | ns       |
|  |                                       | C <sub>L</sub> = 15pF | 5                   | 14  | -              | -             | -              | ns       |
|  |                                       | CL = 50pF             | 6                   | -   | 30             | 37            | 45             | ns       |
| Propagation Delay                                | t <sub>PLZ</sub> , t <sub>PHZ</sub> , | CL = 50pF             | 2                   | -   | 150            | 190           | 225            | ns       |
| OE to Y  | t <sub>PZL</sub> , t <sub>PZH</sub>   | C <sub>L</sub> = 50pF | 4.5                 | -   | 30             | 38            | 45             | ns       |
|  |                                       | C <sub>L</sub> = 15pF | 5                   | 12  | -              | -             | -              | ns       |
|  |                                       | CL = 50pF             | 6                   | -   | 26             | 33            | 38             | ns       |
| Output Transition Times                          | t <sub>TLH</sub> , t <sub>THL</sub>   | C <sub>L</sub> = 50pF | 2                   | -   | 60             | 75            | 90             | ns       |
|  |                                       |                       | 4.5                 | -   | 12             | 15            | 18             | ns       |
|  |                                       |                       | 6                   | -   | 10             | 13            | 15             | ns       |
| Input Capacitance                                | Cl                                    | -                     | -                   | -   | 10             | 10            | 10             | pF       |
| Three-State Output<br>Capacitance                | CO                                    | -                     | -                   | -   | 20             | 20            | 20             | pF       |
| Power Dissipation<br>Capacitance<br>(Notes 3, 4) | C <sub>PD</sub>                       | -                     | 5                   | 45  | -              | -             | -              | pF       |
| HCT TYPES  |                                       |                       |                     |     | !              |               |                | <u> </u> |
| Propagation Delay                                | t <sub>PLH</sub> , t <sub>PHL</sub>   | C <sub>L</sub> = 50pF | 4.5                 | -   | 33             | 41            | 50             | ns       |
| In to Y  |                                       | C <sub>L</sub> = 15pF | 5                   | 13  | -              | -             | -              | ns       |
| Propagation Delay                                | t <sub>PZL</sub> , t <sub>PZH</sub>   | C <sub>L</sub> = 50pF | 4.5                 | -   | 38             | 48            | 57             | ns       |
| S to Y   |                                       | C <sub>L</sub> = 15pF | 5                   | 12  | -              | -             | -              | ns       |
| Propagation Delay                                | t <sub>PLZ</sub> , t <sub>PHZ</sub>   | C <sub>L</sub> = 50pF | 4.5                 | -   | 30             | 38            | 45             | ns       |
| OE to Y  |                                       | C <sub>L</sub> = 15pF | 5                   | 16  | -              | -             | -              | ns       |
| Output Transition Times                          | t <sub>TLH</sub> , t <sub>THL</sub>   | C <sub>L</sub> = 50pF | 4.5                 | -   | 12             | 15            | 18             | ns       |
| Input Capacitance                                | Cl                                    | -                     | -                   | -   | 10             | 10            | 10             | pF       |
| Three-State Output<br>Capacitance                | CO                                    | -                     | -                   | -   | 20             | 20            | 20             | pF       |
| Power Dissipation<br>Capacitance<br>(Notes 3, 4) | C <sub>PD</sub>                       | -                     | 5                   | 45  | -              | -             | -              | pF       |

- 3.  $C_{PD}$  is used to determine the dynamic power consumption, per multiplexer. 4.  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i$  = Input Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.

## Test Circuits and Waveforms

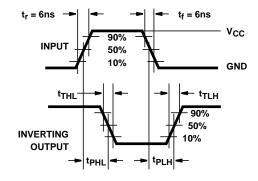


FIGURE 1. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

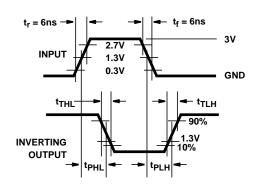


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

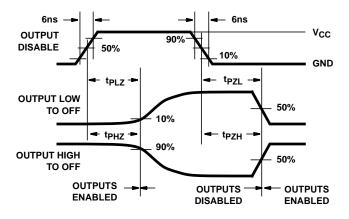


FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM

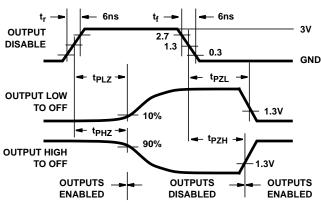
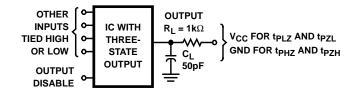


FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms  $t_{PLZ}$  and  $t_{PZL}$  are the same as those for three-state shown on the left. The test circuit is Output  $R_L = 1k\Omega$  to  $V_{CC}$ ,  $C_L = 50pF$ .

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT





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#### **PACKAGING INFORMATION**

| Orderable Device | Status | Package Type | Package | Pins | Package | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Device Marking                  | Samples |
|------------------|--------|--------------|---------|------|---------|----------------------------|------------------|--------------------|--------------|---------------------------------|---------|
|                  | (1)    |              | Drawing |      | Qty     | (2)                        | (6)              | (3)                |              | (4/5)                           |         |
| 5962-8970501EA   | ACTIVE | CDIP         | J       | 16   | 1       | TBD                        | A42              | N / A for Pkg Type | -55 to 125   | 5962-8970501EA<br>CD54HCT257F3A | Samples |
| CD54HC257F3A     | ACTIVE | CDIP         | J       | 16   | 1       | TBD                        | A42              | N / A for Pkg Type | -55 to 125   | 8512401EA<br>CD54HC257F3A       | Samples |
| CD54HCT257F3A    | ACTIVE | CDIP         | J       | 16   | 1       | TBD                        | A42              | N / A for Pkg Type | -55 to 125   | 5962-8970501EA<br>CD54HCT257F3A | Samples |
| CD74HC257E       | ACTIVE | PDIP         | N       | 16   | 25      | Pb-Free<br>(RoHS)          | CU NIPDAU        | N / A for Pkg Type | -55 to 125   | CD74HC257E                      | Samples |
| CD74HC257M       | ACTIVE | SOIC         | D       | 16   | 40      | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -55 to 125   | HC257M                          | Samples |
| CD74HC257M96     | ACTIVE | SOIC         | D       | 16   | 2500    | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -55 to 125   | HC257M                          | Samples |
| CD74HCT257E      | ACTIVE | PDIP         | N       | 16   | 25      | Pb-Free<br>(RoHS)          | CU NIPDAU        | N / A for Pkg Type | -55 to 125   | CD74HCT257E                     | Samples |
| CD74HCT257EE4    | ACTIVE | PDIP         | N       | 16   | 25      | Pb-Free<br>(RoHS)          | CU NIPDAU        | N / A for Pkg Type | -55 to 125   | CD74HCT257E                     | Samples |
| CD74HCT257M      | ACTIVE | SOIC         | D       | 16   | 40      | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -55 to 125   | HCT257M                         | Samples |
| CD74HCT257M96    | ACTIVE | SOIC         | D       | 16   | 2500    | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -55 to 125   | HCT257M                         | Samples |
| CD74HCT257M96G4  | ACTIVE | SOIC         | D       | 16   | 2500    | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -55 to 125   | HCT257M                         | Samples |
| CD74HCT257MG4    | ACTIVE | SOIC         | D       | 16   | 40      | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -55 to 125   | HCT257M                         | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.





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**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF CD54HC257, CD54HCT257, CD74HC257, CD74HCT257:

Catalog: CD74HC257, CD74HCT257

Military: CD54HC257, CD54HCT257

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



## TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
|    | Dimension designed to accommodate the component length    |
|    | Dimension designed to accommodate the component thickness |
|    | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



## \*All dimensions are nominal

| Device        | Package<br>Type | Package<br>Drawing |    |      | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|---------------|-----------------|--------------------|----|------|--------------------------|--------------------------|---------|---------|---------|------------|-----------|------------------|
| CD74HC257M96  | SOIC            | D                  | 16 | 2500 | 330.0                    | 16.4                     | 6.5     | 10.3    | 2.1     | 8.0        | 16.0      | Q1               |
| CD74HCT257M96 | SOIC            | D                  | 16 | 2500 | 330.0                    | 16.4                     | 6.5     | 10.3    | 2.1     | 8.0        | 16.0      | Q1               |





#### \*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CD74HC257M96  | SOIC         | D               | 16   | 2500 | 333.2       | 345.9      | 28.6        |
| CD74HCT257M96 | SOIC         | D               | 16   | 2500 | 333.2       | 345.9      | 28.6        |

# 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



# D (R-PDS0-G16)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



# D (R-PDSO-G16)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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